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2-input NOR Gate



ADE-205-302C (Z)

4th. Edition Feb. 2003

Description

The HD74HCT1G02 is high speed CMOS two input NOR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level.

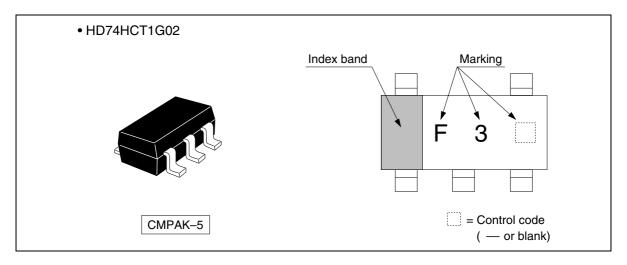
Supply voltage range: 4.5 to 5.5 V

Operating temperature range : -40 to +85°C

- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HCT1G02CME	CMPAK-5 pin	CMPAK-5V	СМ	E (3,000 pcs/reel)

Outline and Article Indication

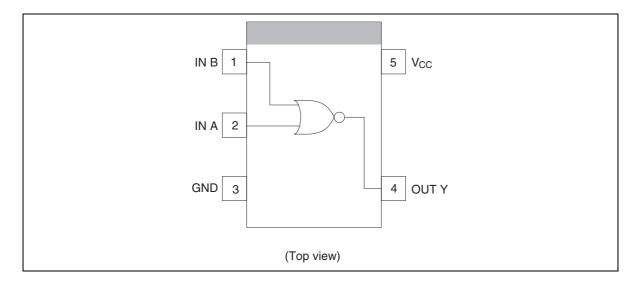


Function Table

Inputs		Output Y
A	В	_
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

H : High level L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range *1	V _I	-0.5 to $V_{cc} + 0.5$	V	
Output voltage range *1,2	V _o	-0.5 to $V_{cc} + 0.5$	V	Output : H or L
Input clamp current	I _{IK}	±20	mA	$V_i < 0 \text{ or } V_i > V_{CC}$
Output clamp current	I _{ok}	±20	mA	$V_o < 0 \text{ or } V_o > V_{cc}$
Continuous output current	Io	±25	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V_{cc} or GND	I _{CC} or I _{GND}	±25	mA	
Maximum power dissipation at Ta = 25°C (in still air) ³	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes:

The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Test Conditions	
Supply voltage range	V _{cc}	4.5	5.5	V		
Input voltage range	V _i	0	5.5	V		
Output voltage range	V _o	0	V _{cc}	V		
Output current	I _{OL}	_	2	mA	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$	
	I _{OH}	_	-2		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$	
Input rise / fall time (0.3 V to 2.7 V)	t _r , t _f	0	500	ns	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$	
Operating temperature	Та	-40	85	°C		

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Item	Symbol	\mathbf{V}_{cc}	T _a = 25	5°C		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		_a = -40 to 85°C Unit		ditions
		(V)	Min	Тур	Max	Min	Max	-		
Input voltage	V_{IH}	4.5 to 5.5	2.0	_	_	2.0	_	V		
	V _{IL}	4.5 to 5.5	_	_	8.0	_	0.8	-		
Output voltage	V _{OH}	4.5	4.4	4.5	_	4.4	_	V	V _{IN} =	$I_{OH} = -20 \mu A$
		4.5	4.18	4.31	_	4.13	_	=	$V_{{}_{\text{IH}}}$ or $V_{{}_{\text{IL}}}$	$I_{OH} = -2 \text{ mA}$
	V _{OL}	4.5	_	0.0	0.1	_	0.1	=		$I_{OL} = 20 \mu A$
		4.5	_	0.17	0.26	_	0.33	=		I _{oL} = 2 mA
Input current	I _{IN}	5.5	_	_	±0.1	_	±1.0	μΑ	V _{IN} = V _{CC} O	r GND
Operating current	I _{cc}	5.5	_	_	1.0	_	10.0	μΑ	$V_{IN} = V_{CC}$ or GND	
Quiescent supply current	I _{CCT}	5.5	_	_	2.0	_	2.9	mA	One input $V_{IN} = 2.4 \text{ V}$, other input V_{CC} or GND	

Switching Characteristics

Item	Symbol	Ta = 25	°C		Unit	Test Conditions		
		Min	Тур	Max				
Output rise / fall time	t _{tlh}	_	5	10	ns	Test circuit		
Propagation delay time	t _{PLH}	_	7.0	12	ns	Test circuit		
	t _{PHL}	_	9.8	17				

$$(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{cc} = 5 \text{ V})$$

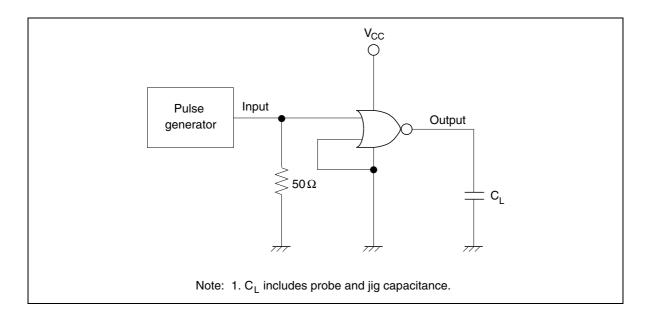
Item	Symbol		Ta = 25°C		Ta = −40 to 85°C		Unit	Test Conditions	
		\mathbf{V}_{cc}	Min	Тур	Max	Min	Max	_	
Output rise / fall time	t _{tlh} t _{thl}	4.5	_	14	25	_	31	ns	Test circuit
Propagation delay time	t _{PLH}	4.5	_	10.6	16	_	20	ns	Test circuit
	t _{PHL}	4.5	_	16.2	27	_	31	_	
Input capacitance	C _{IN}	_	_	2.5	5	_	5	pF	
Equivalent capacitance	C _{PD}	_	_	10	_	_	_	pF	

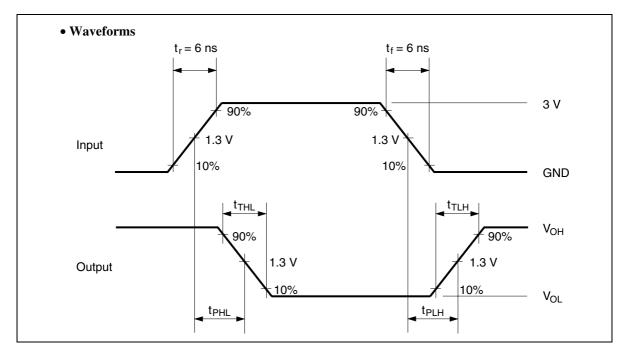
$$(C_L = 50 \text{ pF}, t_r = t_r = 6 \text{ ns})$$

Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

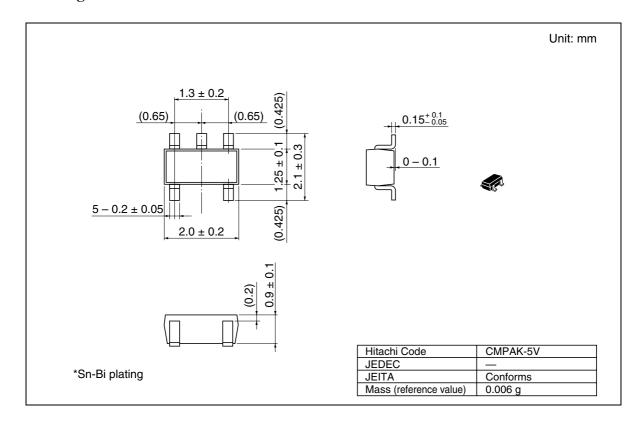
$$I_{\text{cc}}$$
 (opr) = $C_{\text{PD}} \cdot V_{\text{cc}} \cdot f_{\text{IN}} + I_{\text{cc}}$

Test Circuit





Package Dimensions



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